

TÜV MANAGEMENT SERVICE SERVICE

An ISO/TS16949 and ISO 9001 Certified Company

POWER TRANSISTORS

TIP2955 PNP TIP3055 NPN

TO- 3PN Non Isolated Plastic Package

Designed for General Purpose Switching and Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	V_{CEO}	60	V
Collector Emitter Voltage	V_{CER}	70	V
Collector Base Voltage	V_{CBO}	100	V
Emitter Base Voltage	V_{EBO}	7.0	V
Collector Current Continuous	I _C	15	Α
Base Current	l _B	7.0	Α
Total Power Dissipation upto T _c =25°C	P_{D}	90	W
Derate above 25°C		0.72	W/ °C
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	- 65 to +150	°C

THERMAL RESISTANCE

From Junction to case	R _{th (j-c)}	1.39	°C/W
From Junction to Ambient in free air	R _{th (j-a)}	35.7	°C/W

ELECTRICAL CHARACTERISTICS (T_c=25°C unless specified otherwise)

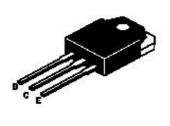
DESCRIPTION	SYMBOL	DL TEST CONDITION		TYP	MAX	UNIT
Collector Emitter Sustaining Voltage	*V _{CEO (sus)}	$I_C=30$ mA, $I_B=0$	60			V
Collector Cut Off Current	I _{CER}	V_{CE} =70V, R_{BE} =100 Ω			1.0	mA
Collector Cut Off Current	I _{CEO}	V_{CE} =30V, I_{B} =0			0.7	mA
Collector Cut Off Current	I _{CEV}	$V_{CE} = 100V, V_{BE(off)} = 1.5V$			5.0	mA
Emitter Cut Off Current	I _{EBO}	V_{BE} =7V, I_{C} =0			5.0	mA
DC Current Gain	*h _{FE}	$I_C=4A, V_{CE}=4V$	20		70	
		$I_C=10A$, $V_{CE}=4V$	5			
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C=4A$, $I_B=400mA$			1.1	V
		$I_{C}=10A, I_{B}=3.3A$			3.0	V
Base Emitter On Voltage	*V _{BE (on)}	$I_C=4A, V_{CE}=4V$			1.8	V

Second Breakdown

Second Breakdown Collector Current		V 00V 1 A N 1111			
With Base Forward Biased	I _{S/b}	V _{CE} =30V, t=1s, Nonrepetitive	3		A

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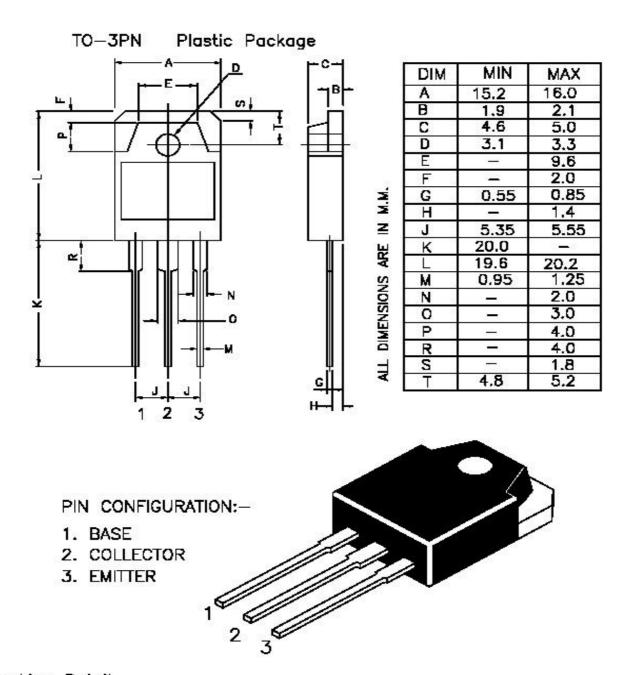
Dynamic Characteristics

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Current Gain Bandwidth Product	f _T	$I_C=0.5A$, $V_{CE}=10V$, $f=1MHz$	2.5			MHz
Small Signal Current Gain	h_{fe}	V_{CE} =4V, I_{C} =1A, f =1KHz	15			

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^{*} Pulse Test: Pulse Width =300ms; Duty Cycle ≤ 2.0%.

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Packing Detail

	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
PACKAGE	Detail	Net Weight/Qty.	Size	Qty.	Size	Qty.	Gr. Wt.
TO-3PN	100pcs/polybag	639gm/100pcs	3"X7.5"X7.5"	0.3K	18"X15"X9"	3K	21kgs

Notes

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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